

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT PTO FORM 1449</b>		Art. Doc. No. <b>10191/2262</b>	Serial No. <b>10/070286</b> To Be Assigned
Applicant <b>Hubert BENZEL et al.</b>			
Filing Date Herewith	<b>7/8/02</b>	Group T Be Assigned	<b>1765</b>

## U. S. PATENT DOCUMENTS

EXAMINER'S INITIALS	PATENT NUMBER	PATENT DATE	NAME	CLASS	SUBCLASS	FILING DATE
<i>WMS</i>	5,725,785*	March 10, 1998	Ishida et al.			

\*Copy of reference is not enclosed because reference is cited in Search Report (copy of reference provided by International Searching Authority).

## FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION	
						YES	NO
<i>WMS</i>	WO 98/53351*	Nov. 26, 1998	PCT				
	1 079 431*	Feb. 28, 2001	EP				
	0 867 921*	Sept. 30, 1998	EP				

\*Copy of reference is not enclosed because reference is cited in Search Report (copy of reference provided by International Searching Authority).

## OTHER DOCUMENTS

EXAMINER'S INITIALS		AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.
<i>WMS</i>		Rinke et al., "Quasi-Monocrystalline Silicon for Thin-Film Devices," Applied Physics A: Materials Science and Processing, Springer Verlag, Berlin, Federal Republic of Germany (June 1999).

\*Copy of reference is not enclosed because reference is cited in Search Report (copy of reference provided by International Searching Authority).

EXAMINER	<i>Anita Slawler</i>	DATE CONSIDERED	<i>6/27/04</i>
EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			